

30V N-Channel Enhancement Mode MOSFET

Voltage 30 V Current 35 A

Features

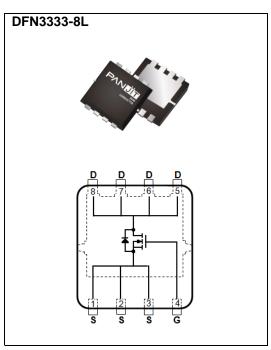
- $R_{DS(ON)}$, $V_{GS}@10V$, $I_D@10A<12m\Omega$
- $R_{DS(ON)}$, $V_{GS}@4.5V$, $I_{D}@5A$ < $18m\Omega$
- High switching speed
- Improved dv/dt capability
- Low gate charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

• Case: DFN3333-8L Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.03 grams



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V _{DS}	30	V	
Gate-Source Voltage		V _{GS}	<u>+</u> 20	V	
Continuous Drain Current	Tc=25°C	I _D	35	А	
	Tc=100°C		23		
Pulsed Drain Current(Note 1)	Tc=25°C	I _{DM}	140		
Power Dissipation	Tc=25°C	Po	27	W	
	Tc=100°C		11		
Continuous Drain Current	T _A =25°C	l _D	10	Α	
	T _A =70°C		8		
Power Dissipation	T _A =25°C		2.0	W	
Power Dissipation	T _A =70°C	Pb	1.3		
Operating Junction and Storage Temperature Range		T_{J} , T_{STG}	-55~150	°C	
Typical Thermal Resistance ^(Note 4,5)	Junction to Case	$R_{ heta JC}$	4.6	°C/W	
	Junction to Ambient	$R_{\theta JA}$	62.5		

Limited only By Maximum Junction Temperature



Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	BVDSS VGS=0V,ID=250uA VGS(th) VDS=VGS,ID=250uA		-	-	V
Gate Threshold Voltage	$V_{GS(th)}$			1.53	2.5	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V,I _D =10A	-	9.7	12	mΩ
		V _{GS} =4.5V,I _D =5A	-	13	18	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =30V,V _{GS} =0V	-	-	1.0	uA
Gate-Source Leakage Current	Igss	V _{GS} = <u>+</u> 20V,V _{DS} =0V	-	-	<u>+</u> 100	nA
Dynamic ^(Note 6)						
Total Gate Charge	Q_g	V _{DS} =15V, I _D =5A, V _{GS} =4.5V ^(Note 3)	-	7.1	-	nC
Gate-Source Charge	Q_gs		-	2.0	-	
Gate-Drain Charge	Q_gd		-	2.8	-	
Input Capacitance	Ciss	V _{DS} =25V, V _{GS} =0V,	-	660	-	pF
Output Capacitance	Coss		-	92	-	
Reverse Transfer Capacitance	Crss	f=1.0MHZ	-	71	-	
Turn-On Delay Time	td _(on)	\/ 45\/ 40	-	6.7	-	ns
Turn-On Rise Time	t _r	V_{DD} =15V, I_{D} =1A, V_{GS} =10V, R_{G} =6 Ω (Note 3)	-	11	-	
Turn-Off Delay Time	td _(off)		-	27	-	
Turn-Off Fall Time	t _f	(Note o)	-	8.3	-	
Drain-Source Diode						
Maximum Continuous Drain-Source	,		-	-	35	А
Diode Forward Current	Is					
Diode Forward Voltage	V_{SD}	I _S =1A,V _{GS} =0V	-	0.71	1.0	V

NOTES:

- 1. Pulse width<300us, Duty cycle<2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature TJ(MAX)=150°C. Ratings are based on low frequency and duty cycles to keep initial TJ =25°C.
- 4. The maximum current rating is package limited.
- 5. R_{OJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. Guaranteed by design, not subject to production testing.



TYPICAL CHARACTERISTIC CURVES

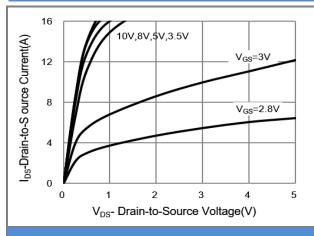


Fig.1 On-Region Characteristics

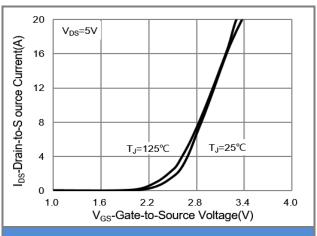


Fig.2 Transfer Characteristics

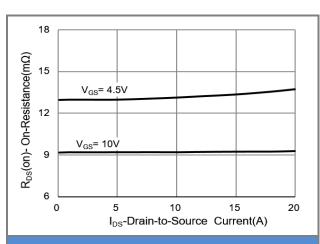


Fig.3 On-Resistance vs. Drain Current

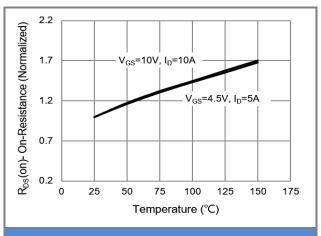


Fig.4 On-Resistance vs. Junction temperature

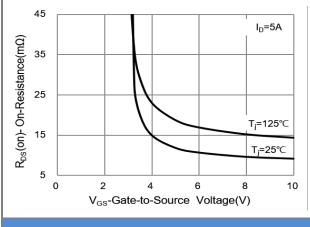


Fig.5 On-Resistance Variation with VGS.

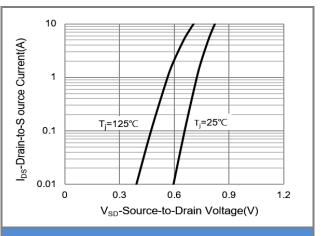


Fig.6 Source-Drain Diode Forward Voltage



TYPICAL CHARACTERISTIC CURVES

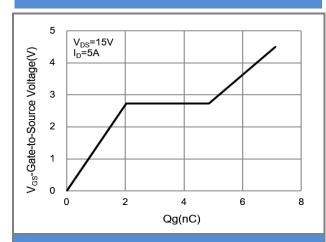


Fig.7 Gate-Charge Characteristics

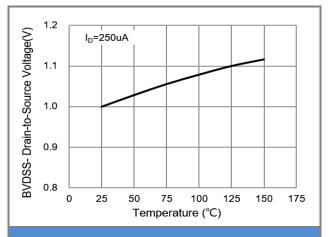


Fig.8 Breakdown Voltage Variation vs. Temperature.

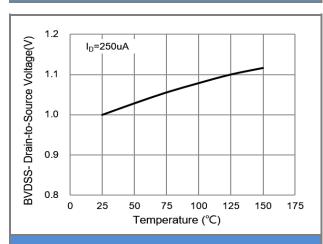


Fig.9 Threshold Voltage Variation with Temperature

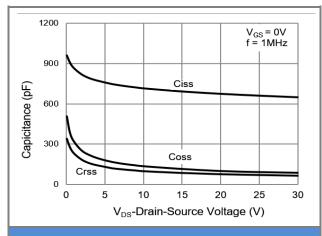


Fig.10 Capacitance vs. Drain-Source Voltage.

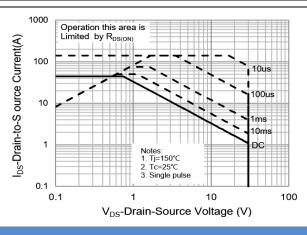


Fig.11 Maximum Safe Operating Area



TYPICAL CHARACTERISTIC CURVES

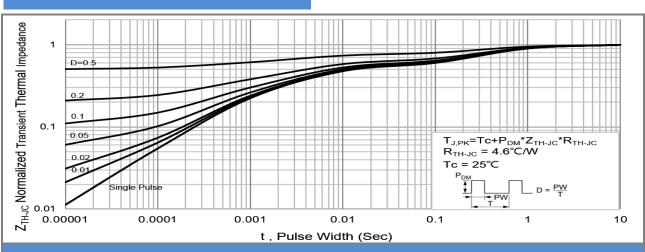


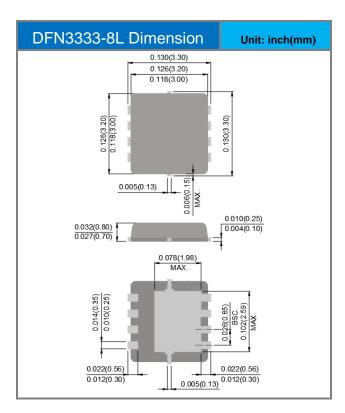
Fig.12 Normalized Transient Thermal Impedance vs. Pulse Width

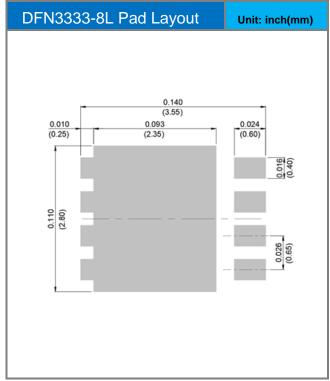


Part No. Packing Code Version

Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJQ4410P_R2_00001	DFN3333-8L	5K pcs / 13" reel	4410	Halogen free RoHS compliant

Packaging Information & Mounting Pad Layout







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